

深圳市嘉佰达电子科技有限公司

SHENZHEN JIABAIDA ELECTRONICS TECHNOLOGY.CO.,LTD

产品规格书

Product specification

客户名 (CUSTOMER):

产品名 (SAMPLE NAME): 8-21 串 200A 同口软件板

产品型号 (MODEL NAME): JBD-SP21S001V1.0 铁锂系列

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智能・只为锂电安全

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1.产品简介(Product introduction)

●JBD-SP21S001 是专门针对 8-21 串储能锂电池包而设计的软件保护板方案,该产品采用新唐采集芯片与上海先积的 MCU 架构,部分参数可以根据客户需求,通过上位机灵活调整。

●JBD-SP21S001 is a software protection board scheme specially designed for 21 strings of lithium battery packs. The product adopts architecture of front-end acquisition chip by **NUVOTON** and MCU by **INEARIN**, and some parameters can be flexibly adjusted through the host computer according to customer needs.

2.功能配置(Configuration)

功能(Function)	配置(Configuration)	功能(Function)	配置(Configuration)		
支持串数 (Number of strings supported)	8~21S	485 通讯(隔离) 485 communication (isolated)	不支持 (Not Standard option)		
持续电流	200A	UART 接口(隔离)	不支持		
(Continuous current)		UART interface (isolated)	(Not supported)		
NTC 数量	1 路内置,二路外置	CAN 通讯	不支持		
(Number of NTC)	(1 built-in, 2 external)	(CAN communication)	(Not Supported)		
均衡功能	被动均衡	232 通讯	不支持		
(Balance Function)	(Passive balance)	(232 Communication)	(Not supported)		
UART 接口(非隔离)	标配	加热膜功能	不支持		
UART (non-isolated)	(Standard option)	(Heating function)	(Not supported)		
开关功能	选配	蓝牙模块	支持		
(Switch function)	(Optional)	(Module of Bluetooth)	(Supported)		
充电限流功能	不支持	电池组串联	不支持		
(Charging current limit)	(Not supported)	(Battery packs in series)	(Not supported)		
电池组并联	不支持	二次保护功能	不支持		
(Battery packs in parallel)	(Not supported)	(Secondary protection)	(Not supported)		
履历	支持	LCD 显示屏	不支持		
(History storage)	(Supported)	(LCD display)	(Not supported)		
预放电功能	不支持	LED 指示灯接口	不支持		
(Pre-discharge function)	(Not Supported)	(Interface of LED indicator)	(Not supported)		
蜂鸣 器	不支持	GPS 接口	不支持		
(Buzzer)	(Not supported)	(Interface of GPS)	(Not supported)		



3.参数设置(Parameter Setting)

3.1.基本参数(Basic parameter)

电芯规格(Cell specifications)	8~21 串铁锂(8~21 strings of LiFePO ₄ battery)					
接口类型(Interface type)	充放电同口(Charge and discharge are both at the same port)					
充电电压(Charging voltage)	3.60V*串数(3.60V*Number of strings)					
单体电压范围(Cell voltage range)	2.20~3.75V					
持续充电电流(Continuous charging current)	200A					
持续放电电流(Continuous discharging current)	200A					
运行功耗(Consumption of running)	≤20mA					
休眠功耗(Consumption of sleep)	≤300uA					
休眠条件(Sleep conditions)	断开开关或无电流\通讯\保护状态下延时 1min±20s Delay 1min±20s under no current \ communication \ protection state					
回路内阻(Circuit resistance)	≤10mR					
工作温度(Operating temperature)	-20℃~75℃					
保护板结构尺寸(Structure size of PCB)						
尺寸(size)	148±2mm * 92±1mm * 23±2mm (长度*宽度*高度) (Length*Width*Height)					

注:测试需在温度 25±2°C,相对湿度 65±20%的环境

Note: Test should be at temperature25±2°C, and relative humidity 65±20% of surroundings.



3.2.主要参数(Main parameter)

第月代Project)			规格	& />-								
対策保护部氏(Over-vortinge release)		项目(Project)				单位 (Unit)						
対策保持版にOver-voltage delays		讨充保护电压(Over-voltage)				V						
対象性数(Over-voltage release)												
注意保护电压(Under-voltage)												
対象決定機能の		•										
対策保护教法件 (Under-voltage release Conditions)						mS						
(Under-voltage release conditions) ***			2.500	2.600	2.700	V						
漢語和文医保护 (Over-current Charge protection value) (Over-current Charge protection value) (Over-current Charge protection value below) (Over-current Charge delay) (Over-current Charge releases conditions) (Over-current Charge releases conditions) (Automatic recover after a delay of 225) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value below) (Refer to configuration table of over-current protection value) (Refer to configuration table of over-curren		过放保护释放条件		电压自恢复或	 充电恢复	1						
英型型藻原質 (Over-current Charge protection value) (Refer to configuration table of over-current protection value below) value below) value below) な知能を関われている。		(Under-voltage release conditions)				narging)						
(Over-current Charge protection value) Descriptions and dinder-voltage protection and dinder-voltage protection (Over-current Charge delay) Description of the protection of the protection of prot		· · · · · · · · · · · · · · · · · · ·										
The content of th	讨压和欠压促拉											
(Over-current Charge delay) 5 10 15 S	(Over-voltage and Under-voltage	大山 十次 7.TH		value bei	ow)							
(Over-current Charge release conditions) - 他教皇世法保护策争 (Refer to configuration table of over-current protection value below) - 母教皇世法保护理会 (Refer to configuration table of over-current protection value below) - 母教皇世法保护理会 (Refer to configuration table of over-current protection value below) - 母教皇世法保护理会 (Refer to configuration table of over-current protection value below) - 母教皇世法保护理会 (Refer to configuration table of over-current protection value below) - 母教皇世法介持护理会 (Refer to configuration table of over-current protection value below) - 母教皇世法介持护理会 (Refer to configuration table of over-current protection value below) - 母教皇神教皇 (Pover-current Discharge delay) 50 - 360 mS - 母教皇神教皇 (Pover-current Discharge delay) 50 mS - 母教皇神教皇 (Pover-current Discharge release) (Refer to configuration table of over-current protection value below) - 母教皇神教皇 (Short discust protection delay time) 200 - 500 uS - 母教皇神教皇 (Short discust protection release) (Refer to configuration table of over-current protection value below) - 母教皇神教皇 (Short circuit protection release) (Refer to configuration table of over-current protection value below) - 母教皇神教皇 (Short circuit protection release value) - 母教皇神教皇 (Short-circuit description release value) - 女皇母母母教皇 (Charging high temperature protection testing is not recommended.) - 女皇母母母教皇 (Charging high temperature protection release value) - 女皇母母母教皇 (Charging low temperature protection release value) - 女皇母母母教皇 (Discharge low temperature protection release value) - 女皇母母母教皇 (Discharge low temperature protection release value) - 女母母母母母母母母教皇 (Discharge low temperature protection release value) - 女母母母母母母母母母母母母母母母母母母母母母母母母母母母母母母母母母母母		• • • • • •	5	10	15	S						
(Automatic recover after a delay of 32S) — 公政电过流保护程度 (1th Over-current Discharge value) — 《政电过流保护程程 (1th Over-current Discharge delay) — 《政电过流保护程程 (2th Over-current Discharge delay) — "数重电过流保护程程 (2th Over-current Discharge delay) — "数重电过流保护程程 (2th Over-current Discharge delay) — "数重电过流保护程程 (2th Over-current Discharge delay) — "数电过流保护程度特 (2th Over-current Discharge delay) — "数电过流保护程度特 (2th Over-current Discharge delay) — "数据使打电流 (Refer to configuration table of over-current protection value below) — "数据使力性 (Over-current Discharge delay) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力中记 (Refer to configuration table of over-current protection value below) — "数据使力性" (Refer to configuration table of over-current protection value below) — "数据使力性" (Refer to configuration table of over-current protection value below) — "数据使力性" (Refer to configuration table of over-current protection value below) — "数据使力性" (Refer to configuration table of over-current protection value below) — "数据使用处理的" (Refer to configuration table of over-current protection value below) — "数据使用处理的" (Refer to configuration table of over-current protection value below) — "数据使用处理的" (Refer to configuration table of over-current protection value below) — "数据使用处理的" (Refer to configuration table of over-current protection value below) — "数据使用处理的" (Refer to configuration table of over-current protection value) — "数据使用处理的" (Refer to configuration table above circuit protection value) — "数	protection)			 延时 32S 后自] 动恢复							
一級放电过速保护值			(Autom			2S)						
(the Over-current Discharge value) - 规章电过速保护程程 (2th Over-current Discharge delay) - 记额电过速保护电流值 (2th Over-current Discharge delay) - 二级放电过速保护电流值 (2th Over-current Discharge delay) - 二级放电过速保护电流值 (2th Over-current Discharge delay) - 正数放电过速保护板塞条件 (Over-current Discharge delay) - 一 360 mS - 260 mS - 270 mS - 2		•				,						
(th Over-current Discharge delay) 「会談电过流保护庭院 (Refer to configuration table of over-current protection value below) 「会談电过流保护政府 (Refer to configuration table of over-current protection value below) 「会談电过流保护政府 (Refer to configuration table of over-current protection value below) 「会談電対流保护政府 (Automatic recover after a delay of 32S) (Automatic recover after a del			(Refer to conf	figuration table	of over-current	protection						
(1th Over-current Discharge delay)		,		value bel	ow)							
(Refer to configuration table of over-current protection yalue below) - 级放电过流保护电流 (Refer to configuration table of over-current protection yalue below) - 级放电过流 (Refer to configuration table of over-current protection yalue below) - 级放电过流 (Refer to configuration table of over-current protection yalue below) - 级放电过流保护变条件 (Over-current Discharge delay) - 级成保护亚深护变条件 (Over-current Discharge release) - 经济化 (Refer to configuration table of over-current protection yalue below) - 经济化 (Refer to configuration table of over-current protection yalue below) - 经济化 (Refer to configuration table of over-current protection yalue below)			5	10	15	s						
Charging high temperature protection value Septiment Septi		(1th Over-current Discharge delay)										
(2th Over-current Discharge value) - 一级宽电过流足保护延迟 - 一级宽电过流足够短条件 (Over-current Discharge delay) - 京田 过滤保护电流 (Short circuit protection current value) - 京田 证据 protection delay time) - 京田 证据 protection delay time) - 京田 证据 protection tricuit protection cere protection to fail, and the short-circuit protection to fail, and the short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent correction is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection to fail, and the short-circuit urent exceeds 2800A, short-circuit protection is not guiaranteed, and short-circuit protection is not guiaranteed, and short-circuit protection is not guiaranteed, and short-circuit protection value) - 京电高温保护精效值 (Charging liph temperature protection value) - 京电温保护程 (Discharge high temperature protection value) - 京电温保护程 (Discharge high temperature protection value) - 京电温保护程 (Discharge liph temperature protection value) - 京电温保护释放值 (Discharge liph temperature protection value) - 京电温保护释放值 (Discharge low temperature protection		二级放电讨流保护电流值										
一級放电対流 2 保护延迟 50			(Refer to conf	•		protection						
(2th Over-current Discharge delay)		一切分中计次文件技术中		value bei	ow)							
横野保护 (Over-current Discharge release) (Automatic recover after a delay of 32S)			50	-	360	mS						
(Over-current Discharge release)				 延时 32S 后貞	 3动恢复							
短路保护电流 (Short circuit protection current value) 超路保护 (Short Circuit Protection) 超路保护変数时候 (Short Circuit Protection) 超路保护疾数			(Autom			2S)						
(Short circuit protection current value) // (Short Circuit Protection) // (Short Circuit Protection Pelas Part Protection Protec		短路保护由流										
短路保护 (Short Circuit Protection) (Short circuit protection delay time) (Short circuit protection recovery) (Short Circuit description: The short-circuit current is less than the minimum value or higher than the maximum value, which may cause the short-circuit protection to fail, and the short-circuit current exceeds 2800A, short-circuit protection is not guaranteed, and short-circuit protection testing is not recommended.) 京电高温保护值 (Charging high temperature protection value) 京电高温保护值 (Charging low temperature protection release value) 京电高温保护值 (Charging low temperature protection release value) 京电流温保护值 (Charging low temperature protection release value) 京电流温保护值 (Discharge high temperature protection value) 京电流温保护程 (Discharge high temperature protection value) 京电流温保护程 (Discharge low temperature protection release value) ②	(Short Circuit											
(Short circuit protection delay time) 200 - 500 us mp		,		value be	low)							
接路保护 (Short Circuit Protection) 短路保护恢复			200	-	500	uS						
(Short circuit protection recovery) Recover by releasing load after approximately 5s 短路设施 短路保护 短路 で			B	 新开负载后约 5	L 秒自动释放							
短路说明: 短路电流小于最小值或高于最大值可能会造成短路保护失效,短路电流超过2800A,不保证有短路保护,也不建议做超路保护测试。 (Short-circuit description: The short-circuit current is less than the minimum value or higher than the maximum value, which may cause the short-circuit protection to fail, and the short-circuit current exceeds 2800A, short-circuit protection is not guaranteed, and short-circuit protection testing is not recommended.) **Tetalizaria for the short circuit protection testing is not recommended.** **Tetalizaria for the short circuit protection release value) **Tetalizaria for the short circuit protection value) **Tetalizaria for the short circuit current is less than the minimum value or higher than the maximum value, short circuit current exceeds 2800A, short-circuit protection is not guaranteed.** **Tetalizaria for the short-circuit protection release value) **Tetalizaria for the short-circuit protection value) **Tetalizaria for the short-circuit protection value) **Tetalizaria for the short-circuit current exceeds 2800A, short-circuit protection is not guaranteed.** **Tetalizaria for the short-circuit protection value) **Tetalizaria for the short-circuit exceeds 2800A, short-circuit protection is not guaranteed.** **Tetalizaria for the short-circuit protection value) **Tetalizaria for the short-circuit protection value) **Tetalizaria for the short-circuit protection value) **Tetaliza						ately 5s						
(Short-circuit description: The short-circuit current is less than the minimum value or higher than the maximum value, which may cause the short-circuit protection to fail, and the short-circuit current exceeds 2800A, short-circuit protection is not guaranteed, and short-circuit protection testing is not recommended.) **Tetes=algkpte** (Charging high temperature protection value) **Tetes=algkpte** (Charging high temperature protection release value) **Tetes=algkpte** (Charging high temperature protection release value) **Tetes=algkpte** (Charging high temperature protection value) **Tetes=algkpte** (Charging high temperature protection value) **Tetes=algkpte** (Charging low temperature protection value) **Tetes=algkpte** (Discharge high temperature protection value) **Tetes=algkpte** (Discharge low temperature pr	Protection)	短路说明: 短路电流小于最小值或高于最大值可能会造成短	路保护失效,短路电流超过 2800A ,不保证有短路保护,也不									
which may cause the short-circuit protection to fail, and the short-circuit current exceeds 2800A, short-circuit protection is not guaranteed, and short-circuit protection testing is not recommended.) **Renear Reprise (Charging high temperature protection value)												
Not guaranteed, and short-circuit protection testing is not recommended.												
A 定 高温保护值 (Charging high temperature protection value) 62 65 68 °C A 定 高温保护释放值 (Charging high temperature protection release value) 52 55 58 °C A 定 任無温保护值 (Charging low temperature protection value) -33 -30 -27 °C A 定 经 经 经 经 经 经 经 经 经 经 经 经 经 经 经 经 经 经		which may cause the short-circuit protection to fail, and the short-circuit current exceeds 2800A , short-circuit protection is not guaranteed, and short-circuit protection testing is not recommended.)										
(Charging high temperature protection value)				0.5								
(Charging high temperature protection release value)			62	65	68	C						
(Charging high temperature protection release value)		充电高温保护释放值	52	55	58	°C						
(Charging low temperature protection value)		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	32	33	30	Ŭ						
流电低温保护释放值 (Charging low temperature protection release value)-28-25-22°C放电高温保护值 (Discharge high temperature protection value) 放电高温保护释放值 (Discharge high temperature protection release value)727578°C位Discharge high temperature protection value) 放电低温保护值 (Discharge low temperature protection value) 放电低温保护释放值 (Discharge low temperature protection value)-33-30-27°C(Discharge low temperature protection value) 所足下高温保护值 (FET high temperature protection value)-28-25-22°CFET 高温保护值 (FET high temperature protection value)859095°CFET 高温保护释放值 (FET high temperature protection release value)657075°C均衡开启电压 (Balance function turn-on voltage)3.273.303.33V功衡可能 (Balance Function)日150mV			-33	-30	-27	°C						
Charging low temperature protection release value 128 125												
温度保护 (Short Circuit Discharge)放电高温保护権 (Discharge high temperature protection value)727578°C放电高温保护释放值 (Discharge high temperature protection release value)626568°C放电低温保护值 (Discharge low temperature protection value) 放电低温保护释放值 (Discharge low temperature protection release value)-33-30-27°CFET 高温保护程位 (FET high temperature protection release value)859095°CFET 高温保护程放值 (FET high temperature protection release value)657075°C方衡开启电压 (Balance function turn-on voltage)3.273.303.33V均衡功能 (Balance Function)开启压差 (Difference opening voltage value)15mV			-28	-25	-22	°C						
(Discharge high temperature protection value) (Short Circuit Discharge) (Discharge high temperature protection value) 放电低温保护释放值 (Discharge high temperature protection release value) 放电低温保护值 (Discharge low temperature protection value) 放电低温保护释放值 (Discharge low temperature protection value) 亦电低温保护释放值 (Discharge low temperature protection release value) FET 高温保护值 (FET high temperature protection value) FET 高温保护释放值 (FET high temperature protection release value) FET 高温保护释放值 (FET high temperature protection release value) 50 0 95 °C FET 高温保护释放值 (FET high temperature protection release value) 50 70 75 °C FET 高温保护释放值 (Balance function turn-on voltage) 「特殊开启电压 (Balance function turn-on voltage) 70 0 75 °C FAGE WW Difference opening voltage value)	App. edu. ()		70	7.5	70	°0						
Discharge) MRURIC ACC (Discharge high temperature protection release value) MRURIC ACC (Discharge high temperature protection release value) MRURIC ACC ACC		(Discharge high temperature protection value)	12	/5	/8	C						
(Discharge high temperature protection release value)		放电高温保护释放值	62	65	68	°C						
(Discharge low temperature protection value)	Diodilai go)		02	00	00							
放电低温保护释放值 (Discharge low temperature protection release value) FET 高温保护值 (FET high temperature protection value) FET 高温保护解放值 (FET high temperature protection value) FET 高温保护释放值 (FET high temperature protection release value) 均衡开启电压 (Balance function turn-on voltage) サ海功能 (Balance Function) 均衡电流 150 mA			-33	-30	-27	°C						
(Discharge low temperature protection release value) FET 高温保护値 (FET high temperature protection value) FET 高温保护解放値 (FET high temperature protection release value) 「FET 高温保护解放値 (FET high temperature protection release value) 均衡开启电压 (Balance function turn-on voltage) Thack (Difference opening voltage value) 均衡电流 「Difference opening voltage value) 「Difference opening voltage value) 「Table Table Ta												
FET 高温保护值 (FET high temperature protection value) FET 高温保护释放值 (FET high temperature protection release value) 均衡开启电压 (Balance function turn-on voltage) 均衡可能 (Difference opening voltage value) 均衡电流 FET 高温保护释放值 65 70 75 °C 3.27 3.30 3.33 V mV			-28	-25	-22	°C						
(FET high temperature protection value) FET 高温保护释放值 (FET high temperature protection release value) 均衡开启电压 均衡开启电压 (Balance function turn-on voltage) 力衡功能 (Balance Function) 均衡电流 150 mA			OE.	00	OE.	°C						
(FET high temperature protection release value) 55 70 75 C		(FET high temperature protection value)	85	90	90	C						
(FET high temperature protection release value) 均衡开启电压 (Balance function turn-on voltage) 开启压差 (Difference opening voltage value) 均衡电流 150 mA			65	70	75	°C						
(Balance function turn-on voltage) 3.27 3.30 3.33 V mV (Balance Function)												
均衡功能 开启压差 15 mV (Difference opening voltage value) 均衡电流 150 mA			3.27	3.30	3.33	V						
(Balance Function) (Difference opening voltage value) 15 mV	均衡功能	, , ,										
均衡电流 100 150 mA				15		mV						
(Balance current)	,		100		150	mΛ						
		(Balance current)	100		120	IIIA						



均衡模式	静态均衡
(Balance model)	(Idle equalization)
均衡类型	脉冲模式
(Balance type)	(Pulsed model)

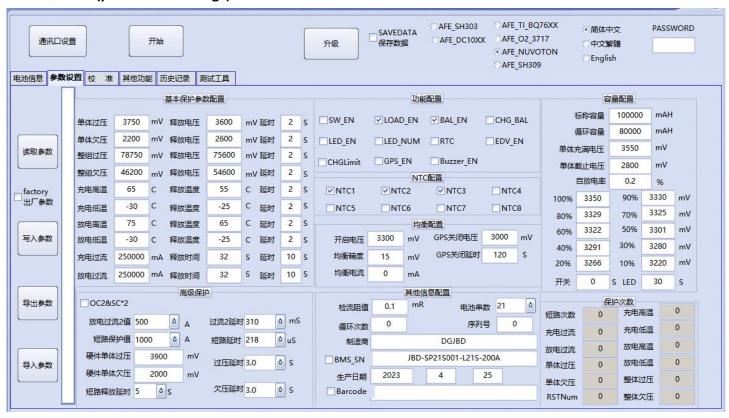
注:测试需在温度 25±2°C, 相对湿度 65±20% 的环境。

Note: Test should be at temperature25±2°C, and relative humidity 65±20% of surroundings.

过流保护值配置表(Over-current protection value configuration table)

	电流 us current)	充电过流保护值	一级放电过流保护值 (1 st discharge Over-current	二级放电过流保护值 (The second discharge	短路保护值 (Short circuit protection value)	
Charge	Discharge	(Charge Over-current value)	value)	Over-current value)		
200A	200A	250±10A	250±10A	500±100A	1420±200A	

3.3.参数设置(parameter settings)



JBD-SP21S001-L21S-200A-200A

The diagram of the host computer

*注意事项:

- 1.上位机为 JBDTOOLS V3.6 或以上版本,右上角区域选择芯片"AFE NUVOTON"。
- 2.上位机与 BMS 通讯时,需要保证接线规则正确,且需保证硬件地址与上位机地址一致。

*Attention:

- 1. The version of software in upper computer is **JBDTOOLS V3.6 or above**, and please choose the 'AFE_NUVOTON' at top right corner.
- 2. When the upper computer communicates with the BMS, it is necessary to ensure that the wiring rules are correct and that the hardware address is consistent with the upper computer.

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4.功能说明(Function Description)

4.1.过充保护和恢复(Overcharge protection and recovery)

4.1.1.单体过充保护及恢复(Cell overcharge protection and recovery)

当任意一节电芯电压高于单体过充电压设定值,并且持续时间达到单体过充延时,系统进入过充保护状态,关闭充电 MOS,不能对电池充电。

单体过充保护后,当所有单体电压降到单体过充恢复值以下时,解除过充保护状态。也可放电解除。

When the voltage of any cell is higher than the set value of the cell overcharge voltage, and the duration reaches the cell overcharge delay, the system enters the overcharge protection state, the charging MOS will turn off, and the battery cannot be charged.

After the cell overcharge protection, when the voltage of all cells drops below the cell overcharge recovery value, the overcharge protection state is released. It can also be released by discharge.

4.1.2. 总体过充保护及恢复(Entire overcharge protection and recovery)

当总体电压高于总体过压设定值,并且持续时间达到总体过充延时,系统进入过充保护状态,关闭充电 MOS,不能对电池充电。

当总体电压降到总电压过压保护恢复值以下时,解除过充保护状态,也可放电解除。

When the entire voltage is higher than the entire Over-voltage set value, and the duration reaches the entire overcharge delay, the system enters the overcharge protection state, turns off the charging MOS, and cannot charge the battery.

When the entire voltage drops below the recovery value of the entire voltage Over-voltage protection, the overcharge protection state is released, and it can also be released by discharge.

4.2.过放保护和恢复(Over-discharge protection and recovery)

4.2.1.单体过放保护及恢复(Cell over-discharge protection and recovery)

当最低节电压低于单体过放电压设定值,并且持续时间达到单体过放延时,系统进入过放保护状态,关闭放电 MOS,不能对电池放电。

发生单体过放保护后,对电池组充电可以解除过放保护状态。

When the minimum cell voltage is lower than the set value of the over-discharge voltage of the cell, and the duration reaches the over-discharge delay of the cell, the system enters the over-discharge protection state, turns off the discharge MOS, and cannot discharge the battery.

After the cell over-discharge protection occurs, charging the battery pack can release the over-discharge protection state.

4.2.2.总体过放保护及恢复(Entire over-discharge protection and recovery)

当总体电压低于总体过放电压设定值,并且持续时间达到总体过放延时,系统进入过放保护状态,关闭放电 MOS,不能对电池放电。

发生总体过放保护后,对电池组充电可以解除过放保护状态。

When the entire voltage is lower than the entire over-discharge voltage set value, and the duration reaches the entire over-discharge delay, the system enters the over-discharge protection state, turns off the discharge MOS, and cannot discharge the battery.

After the entire over-discharge protection occurs, charging the battery pack can release the over-discharge protection state.

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4.3. 充电过流保护和恢复(Over-current protection and recovery in charging)

当充电电流超过充电过流保护电流且持续的时间达到过流检测延迟时间,系统进入到充电过流保护状态,不能对电池进行充电。发生充电过流保护后延时自动恢复,如需不要自动恢复可将对应的释放时间设长;放电也可以解除充电过流状态。

When the charging current exceeds the charging protection current and the duration reaches the Over-current detection delay time, the system enters the charging Over-current protection state and cannot charge the battery. After the charging Over-current protection occurs, it will automatically recover after a delay. If you want to automatically recover or not, you can set the corresponding release time to be longer; the charging Over-current state can also be released by discharging.

4.4.放电过流保护和恢复(Over-current protection and recovery in discharging)

当放电电流超过放电过流保护电流且持续的时间达到过流检测延迟时间,系统进入到放电过流保护状态,关闭放电 MOS。 发生放电过流后延时自动恢复,如需不要自动恢复可将对应的释放时间设长。充电也可以解除放电过流状态。放电有两级过 流保护功能,对不同的电流值具有不同的响应速度,更加可靠地保护电池。

When the discharge current exceeds the discharge Over-current protection current and the duration reaches the Over-current detection delay time, the system enters the discharge Over-current protection state and turns off the discharge MOS. Delayed automatic recovery after discharge Over-current occurs, and the corresponding release time can be set longer if automatic recovery is required. Charging can also release the discharge Over-current protect condition. Discharge has two-level Over-current protection function, which has different response speeds for different current values, and protects the battery more reliably.

4.5.温度保护和恢复(Temperature Protection and Recovery)

4.5.1.充放电高温保护及恢复(High temperature protection and recovery in charging and discharging)

当充放电时 NTC 检测电芯表面的温度高于设定的高温保护温度时,管理系统进入高温保护状态,充电或放电 MOSFET 关闭,在该状态不能对电池包充电或放电。

当电芯表面的温度下降到高温恢复设定值时,管理系统从高温状态恢复,重新导通充放电 MOS。

When the NTC detects that the temperature of the battery cell surface is higher than the setting of high temperature protection value during charging and discharging, the management system enters the high temperature protection state, the charging or discharging MOSFET is turned off, and the battery pack cannot be charged or discharged in this state.

When the temperature of the surface of the cell drops to the high temperature recovery set value, the management system recovers from the high temperature state and turns on the charge and discharge MOS again.

4.5.2.充放电低温保护和恢复(Low temperature protection and recovery in charging and discharging)

当充放电时 NTC 检测电芯表面的温度低于设定的低温保护温度时,管理系统进入低温保护状态,充电或放电 MOSFET 关闭,在该状态不能对电池包充电或放电。

当电芯表面的温度上升到低温恢复设定值时,管理系统从低温状态恢复,重新导通充放电 MOS。

When the NTC detects that the temperature of the cell surface is lower than the setting of low temperature protection value during charging and discharging, the management system enters the low temperature protection state, the charging or discharging MOSFET is turned off, and the battery pack cannot be charged or discharged in this state.

When the temperature of the cell surface rises to the low temperature recovery set value, the management system recovers from the low temperature state and turns on the charge and discharge MOS again.

4.6.均衡功能(Balance function)

管理系统采用电阻旁路的方式进行电芯均衡, 充电过程中电池组最高节单体电芯电压达到设定的均衡启动电压值, 且电

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池组单体电芯最低电压与最高电压压差大于设定值时,达到条件的电芯均衡功能开启,相邻的两路均衡不能同时开启。 当电芯压差小于设定值或者电芯电压小于均衡开启电压时均衡停止。

The management system uses the resistance bypass method to balance the cells. During the charging process, the voltage of the highest single cell of the battery pack reaches the set equilibrium starting voltage value, and the voltage difference between the minimum voltage and the maximum voltage of the single cell of the battery pack is greater than the set value. When the value is set, the equalization function of the cells that meet the conditions is enabled, and the two adjacent equalizers cannot be enabled at the same time.

The equalization stops when the cell voltage difference is less than the set value or the cell voltage is less than the equalization turn-on voltage.

4.7.容量计算(Capacity calculation)

可以通过对电流、时间积分的方式精准地进行电池组的 SOC 计算。电池组满容量、及循环容量可以通过上位机进行设置,在进行完整充放电循环后容量可自动更新。 具有充放电循环次数计算功能,当电池组累积放电容量达到设定循环容量时,循环次数增加一次。

The SOC calculation of the battery pack can be accurately performed by integrating current and time. The full capacity and cycle capacity of the battery pack can be set through the host computer, and the capacity can be automatically updated after a complete charge and discharge cycle. It has the function of calculating the number of charge and discharge cycles. When the cumulative discharge capacity of the battery pack reaches the set cycle capacity, the number of cycles increases once.

注:新装电池请根据电池容量设定标称容量和循环容量,并进行一次容量学习,否则可能出现容量不准问题。 容量学习操作:先充满电至过压保护,然后放空电至欠压保护,再充一次电即可。

Note: For newly installed batteries, please set the nominal capacity and cycle capacity according to the battery capacity, and conduct a capacity study, otherwise the capacity inaccuracy may occur. Capacity learning operation: first fully charge to Over-voltage protection, then discharge to under-voltage protection, and then charge it again.

4.8.休眠功能(Sleep function)

保护板处于静态时(无通讯,无电流,无均衡及过压保护),且电压值位于 GPS 关闭电压之上,延时 1 分钟后进入休眠状态。而当电压值位于 GPS 关闭电压之下时,保护板会先延时关闭 GPS,之后再进入休眠计时。

进入此状态后,保护板仅降低检测频率和自身功耗。通讯、拨开关、充放电可以自动退出休眠模式。

When the BMS is in static state (no communication, no current, no balance and Over-voltage protection) ,and the voltage value is set above the GPS off voltage. After a delay of 1 minutes, it will enter the sleep state. However, when voltage value is set below the GPS off voltage, the BMS will delay closing the GPS before entering sleep timing.

After entering this state, the BMS will only reduce the frequency of detecting and its own power consumption. Communication, dial switch, charging and discharging can automatically exit the sleep mode.



4.9.通讯功能(Communication)

4.9.1. 串口通讯(Serial Communication)



UART 通讯盒
(UART communication box)



RS485 通讯盒



蓝牙模块

(RS485 communication box)

(Bluetooth module)

注:上述工具都需要另行购买。

Note: The above tools need to be purchased separately.

连接方式:在电脑端安装我司通讯盒专用驱动程序后,将通讯盒的 USB 端插在电脑的 USB 端口,另一头接在已经接好电池的保护板对应接口。打开上位机,点通讯口设置,选择通讯盒对应 CMO 口,其他选项不用动,确认后点击开始,即可读取保护内数据。

如需更改保护板参数,一定要先在参数页面点击读取参数后,再来更改参数。

The connection method: After installing the special driver for our communication box on the computer, insert the USB end of the communication box into the USB port of the computer, and connect the other end to the corresponding interface of the protection board that has been connected to the battery. Open the upper computer, click the communication port settings, select the CMO port corresponding to the communication box, and do not change other options. After confirming, click Start to read the data in the protection.

If you need to change the parameters of the protection board, you must click on the parameter page to read the parameters before changing the parameters.

通讯设置:

●波特率: 9600;

●校验位:无;

●数据位长度:8位;

●停止位长度: 1位

COM Settings:

●Baud rate:9600;

●Parity Bit:NONE;

●Data Bit:8 bits;

●Stop Bit:1 bit



5.主要物料(Main material)

序号 (Number)	物料名称 (Name of Material)	生产厂家 (Manufacturer)	数量 (Quantity)
1	IC\33XT4\SOT89-3	INEARIN(先积)	1PCS
2	IC\QFP\KA49522A\TQFP64L	NUVOTON(新唐)	1PCS
3	MOS\SMD\SS014N10LS\TOLL-8	SKY-SEMI(思开)	28PCS
4	NTC*2\10K\3950\250mm\带端子\HY2.0	仙桥	1PCS
	配件(Accessories)		
1	采集线\7PIN\HY2.0\带卡扣\24AWG\550MM\黑白红		1PCS
2	采集线\15PIN\HY2.0\带卡扣\24AWG\550MM\黑白红		1PCS
3	采集线\4PIN\HY2.0\带卡扣\24AWG\550mm\黑白红		1PCS
4	采集线\2PIN\HY2.0\带卡扣\24AWG\550mm\全白		1PCS

注:以上物料可能用同等规格参数或者更好的规格参数的物料替代,如有认证需求不允许更换物料,需要通知我司业务重新送样,受控规格书,最终解释权归嘉佰达所有。

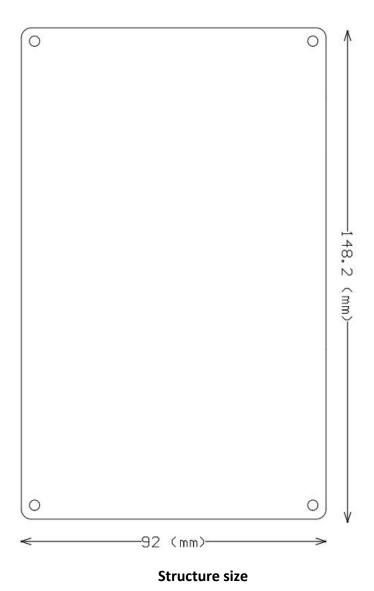
Note: The above materials may be replaced by materials with the same specifications or better specifications. If there are certification requirements, the replacement of materials is not allowed, and we need to notify our business to send samples again. The controlled specifications, the final interpretation right belongs to JBD.

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6.示意图及尺寸(Schematic and Dimensions)

6.1.尺寸及安装点标注图(Dimensions and installation point drawing).





7.信号口定义(Definition of signal port)

7.1.示意图标注接口标号(Illustration annotation)

Schematic marking the interface label (Refer to the following figures)





标号	位号	接插件功能	接插件示意图	PIN	PIN 功能定义	备注
(Label)	(Tag number)	(Connector)	(Schematic diagram)		(Pin function definition)	(Note)
				1	接最低节电芯负极	B-
				_ •	Connect to Negative Side of Cell 1	
				2	接第1节电芯正极	
					Connect to Positive Side of Cell 1 接第 2 节电芯正极	
				3	按第二月电心正恢 Connect to Positive Side of Cell 2	
					接第3节电芯正极	
				4	Connect to Positive Side of Cell 3	
				_	接第4节电芯正极	
				5	Connect to Positive Side of Cell 4	
				6	接第5节电芯正极	
					Connect to Positive Side of Cell 5	
				7	接第6节电芯正极	
	J1	电压检测插座	-		Connect to Positive Side of Cell 6 接第 7 节电芯正极	
1	(HY2.0-15P)	(Voltage detection	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1	8	接弗 / 卫电心正做 Connect to Positive Side of Cell 7	
	(帯卡扣)	socket)	0 5 4 3 2 1		接第8节电芯正极	
				9	Connect to Positive Side of Cell 8	
				40	接第9节电芯正极	
				10	Connect to Positive Side of Cell 9	
				11	接第 10 节电芯正极	
				- ' '	Connect to Positive Side of Cell 10	
				12	接第 11 节电芯正极	
					Connect to Positive Side of Cell 11	
				13	接第 12 节电芯正极 Connect to Positive Side of Cell 12	
					接第 13 节电芯正极	
				14	Connect to Positive Side of Cell 13	
				4-	接第 14 节电芯正极	
				15	Connect to Positive Side of Cell 14	
				1	接第 15 节电芯正极	
				_ '	Connect to Positive Side of Cell 15	
				2	接第 16 节电芯正极	
					Connect to Positive Side of Cell 16	
				3	接第 17 节电芯正极	
	J2	电压检测插座			Connect to Positive Side of Cell 17 接第 18 节电芯正极	
2	(HY2.0-7P)	(Voltage detection	765	4	Connect to Positive Side of Cell 8	
	(帯卡扣)	socket)	. 0 5 4 3 2 1	_	接第 19 节电芯正极	
				5	Connect to Positive Side of Cell 19	
					接第 20 节电芯正极	
				6	Connect to Positive Side of Cell 20	
				7	接第 21 节电芯正极	B+
					Connect to Positive Side of Cell 21	
				1		
	J3					
			/	2	连接温度探头	
3	(HY2.0-4P)	NTC	4321		Connect to the negative temperature	
	(带卡扣)		7321	3	coefficient detector	
				4		
4	J4 (HY2.0-2P)	Switch of discharge	No. of Contract of	1	K +	
4	(帯卡扣)	Switch of discharge	ž i	2	К-	
				1	UART - GND	
5	J5 (HY2.0-4P)	UART	The second second	2	UART - RXD	
5	(带卡扣)	(Non Isolated)	4 3 2 1	3	UART - TXD	
				4	UART - B+	B+
	L	l	l			



7.2.备用配置串数(Configuring alternative Cell counts)

Cell Input	8 S	98	108	118	128	138	148	158	16S	178	18S	198	208	218																	
BC21	Cell 8	Cell 9	Cell 10	Cell 11	Cell 12	Cell 13	Cell 14	Cell 15	Cell 16	Cell 17	Cell 18	Cell 19	Cell 20	Cell 21																	
BC20	Cell 7	Cell 8	Cell 9	Cell 10	Cell 11	Cell 12	Cell 13	Cell 14	Cell 15	Cell 16	Cell 17	Cell 18	Cell 19	Cell 20																	
BC19														Cell 19																	
BC18												Cell 17	Cell 18	Cell 18																	
BC17										Cell 15	Cell 16		Cell 17	Cell 17																	
BC16							0 11 40	Cell 13	Cell 14			Cell 16	Cell 16	Cell 16																	
BC15						Cell 11	Cell 12				Cell 15	Cell 15	Cell 15	Cell 15																	
BC14				Cell 9	Cell 10					Cell 14																					
BC13	0 " 0	Cell 7	Cell 7			_			Cell 13																						
BC12	Cell 6							Cell 12																							
BC11							Cell 11																								
BC10																							Cell 10								
ВС9																				Cell 9	Cell 9	Cell 9	Cell 9	Cell 9	Cell 9	Cell 9	Cell 9	Cell 9	Cell 9		
BC8																			Cell 8	Cell 8	Cell 8	Cell 8	Cell 8	Cell 8	Cell 8						
ВС7			Cell 7																												
BC6		Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6	Cell 6																	
BC5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5	Cell 5																	
BC4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4	Cell 4																	
ВС3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3	Cell 3																	
BC2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2	Cell 2																	
BC1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1	Cell 1																	
							B-																								



8.环境适用性(Environmental suitability)

8.1.工作环境(The environment of working)

●BMS 保护板允许在下列条件下正常工作:

●环境温度: -20°C ~ 75°C;

●相对湿度: 5% ~ 90%;

●大气压力: 86kPa~106 kPa;

•BMS The protective plate allows normal operation under the following conditions:

●Ambient temperature: -20°C ~ 75°C;

●Relative humidity: 5% ~ 90%;

●Atmospheric pressure: 86kPa~106kPa;

8.2.存储环境(The environment of storage)

●BMS 保护板应存储在环境温度为-5°C[~]+40°C、相对湿度不大于 70%、清洁通风良好的库房 内,空气中不得含有腐蚀性气体及影响电气绝缘的介质,不得受任何机械冲击或重压。不受阳光直射,与热源(暖气设备等)之间的距离不得少于 2m。在以上存储条件下,BMS 保护板可存放一年。

●BMS should be stored in a clean and well-ventilated warehouse with an ambient temperature of -5°C~+40°C, a relative humidity of not more than 70%, and the air must not contain corrosive gases and media that affect electrical insulation, and must not be affected by any mechanical Shock or heavy pressure. Not subject to direct sunlight, and the distance from the heat source (heating equipment, etc.) should not be less than 2m. Under the above storage conditions, the BMS protection board can be stored for one year.

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9.包装运输(Packing and shipping)

9.1.标志(Logo)

BMS 保护板应有下列清晰耐久标志:

- ●产品名称、型号
- ●电芯型号
- ●出厂日期及编号

9.2.包装(Package)

- ●包装应符合防潮、防振动的要求,包装箱应牢固可靠,箱内应衬有防潮材料,产品 在箱内不应窜动。
- ●外部纸箱包装箱,单板防静电袋加气泡袋包装;
- •The packaging should meet the requirements of moisture-proof and anti-vibration, the packing box should be firm and reliable, the inside of the box should be lined with moisture-proof material, and the product should not move in the box.
 - External carton box, veneer anti-static bag plus bubble bag packaging;

9.3.运输(transportation)

- ●在运输中,产品不得受剧烈机械冲撞、暴晒、雨淋、化学腐蚀性物品及有害气体侵蚀;在装卸过程中,产品轻搬轻放, 严禁摔掷、重压。
 - ●包装箱码放高度小于 5 层。
- •During transportation, the product shall not be subject to severe mechanical impact, exposure to the sun, rain, chemical corrosive substances and harmful gases; During the loading and unloading process, the product should be handled with care, and it is strictly forbidden to throw or press it.
 - •The height of the packing boxes shall be less than 5 layers.

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10.注意事项(Precautions)

- 1. 本电池管理系统常规是不能串联使用的,需要定制版本才支持串联使用。
- 2. 多个使用本管理系统的电池包并联时,应确保并联之前各电池包的最大压差低于 3V。
- 3. 多个使用本管理系统的电池包并联使用时,适配器总的充电冲击电流可能施加到单个电池包上,应确保适配器总的充电冲击电流不超过单个管理系统充电冲击电流的最大值。
- 4. 本管理系统的短路保护功能适用于多种应用情景,但并不能保证可以在任意条件下短路。当电池包和短路回路的内阻值总和低于 40mΩ、电池组容量超出额定值 20%、短路电流超过 2000A、短路回路的电感非常大或者短路的导线总长度非常长时,请自行测试确定是否可以使用本管理系统。
 - 5. 焊接电池引线时,一定不可有错接或反接。如果确实已接错,这块电路板可能已损坏,需要重新测试合格后才可使用。
 - 6. 装配时管理系统不要直接接触到电芯表面,以免损坏电路板。装配要牢固可靠。
- 7. 使用中注意引线头、烙铁、焊锡等不要碰到电路板上的元器件,否则有可能损坏本电路板。焊接本电路板请不要使用 膏状助焊剂,否则有可能导致本电路板工作不正常。
 - 8. 使用过程要注意防静电、防潮、防水等。
 - 9. 使用过程中请遵循设计参数及使用条件,不得超过本规格书中的值,否则有可能损坏管理系统。
 - 10. 将电池组和管理系统组合好以后,初次上电如发现无电压输出或充不进电,请检查接线是否正确。
 - 11. 本规格书中的参数、功能和外形仅供参考,请以保护板实物为准。
- 1. This battery management system cannot be used in series generally, and requires a customized version to support series use.
- 2. When multiple battery packs using this management system are connected in parallel, make sure that the maximum voltage difference of each battery pack is lower than 3V before parallel connection.
- 3. When multiple battery packs using this management system are used in parallel, the total charging inrush current of the adapter may be applied to a single battery pack. It should be ensured that the total charging inrush current of the adapter does not exceed the maximum charging inrush current of a single management system.
- 4. The short-circuit protection function of this management system is suitable for a variety of application scenarios, but it does not guarantee that it can be short-circuited under any conditions. When the total internal resistance of the battery pack and the short-circuit loop is lower than $40m\Omega$, the capacity of the battery pack exceeds the rated value by 20%, the short-circuit current exceeds 2000A, the inductance of the short-circuit loop is very large, or the total length of the short-circuit wire is very long, please test yourself to determine whether This management system can be used.
- 5. When soldering the battery leads, there must be no wrong or reverse connection. If it is indeed connected incorrectly, the circuit board may be damaged and needs to be re-tested before it can be used.
- 6.When assembling, the management system should not directly touch the surface of the cell to avoid damage to the circuit board. Assembly should be firm and reliable.
- 7.During use, be careful not to touch the components on the circuit board such as lead tips, soldering iron, solder, etc., otherwise the circuit board may be damaged. Please do not use paste flux when soldering this circuit board, otherwise it may cause this circuit board to work abnormally.
 - 8. During use, pay attention to anti-static, moisture-proof, waterproof, etc.
- 9.During use, please follow the design parameters and conditions of use, and must not exceed the values in this specification, otherwise the management system may be damaged.
- 10. After the battery pack and the management system are combined, please check whether the wiring is correct if you find that there is no voltage output or charging fails when the battery is powered on for the first time.
- 11. The Parameter, function and outlook of BMS in this specification are for reference only, please refer to actual product.

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